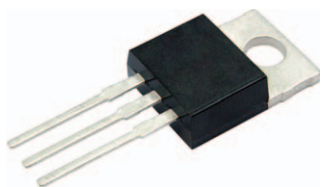
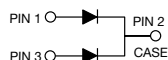


# Dual High Voltage Trench MOS Barrier Schottky Rectifier

Ultra Low  $V_F = 0.57 \text{ V}$  at  $I_F = 5 \text{ A}$

**TMBS®**
**TO-220AB**

**V20M100M**


## FEATURES

- Trench MOS Schottky technology
- Low forward voltage drop, low power losses
- High efficiency operation
- Solder dip 275 °C max. 10 s, per JESD 22-B106
- Material categorization:  
for definitions of compliance please see  
[www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)


**RoHS**  
COMPLIANT

## TYPICAL APPLICATIONS

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection.

## PRIMARY CHARACTERISTICS

$I_{F(AV)}$	2 x 10 A
$V_{RRM}$	100 V
$I_{FSM}$	110 A
$V_F$ at $I_F = 10 \text{ A}$ ( $T_A = 125 \text{ °C}$ )	0.67 V
$T_J \text{ max.}$	175 °C
Package	TO-220AB
Diode variations	Common cathode

## MECHANICAL DATA

**Case:** TO-220AB

Molding compound meets UL 94 V-0 flammability rating  
Base P/N-E3 - RoHS-compliant, commercial grade

**Terminals:** Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

**Polarity:** As markedp

**Mounting Torque:** 10 in-lbs maximum

## MAXIMUM RATINGS ( $T_A = 25 \text{ °C}$ unless otherwise noted)

PARAMETER	SYMBOL	V20M100M	UNIT
Maximum repetitive peak reverse voltage	$V_{RRM}$	100	V
Maximum average forward rectified current (fig. 1)	$I_{F(AV)}$	20	A
		10	
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	$I_{FSM}$	110	A
Voltage rate of change (rated $V_R$ )	$dV/dt$	10 000	V/ $\mu$ s
Operating junction and storage temperature range	$T_J, T_{STG}$	-55 to +175	°C



ELECTRICAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Instantaneous forward voltage per diode	I <sub>F</sub> = 5 A	T <sub>A</sub> = 25 °C	V <sub>F</sub> <sup>(1)</sup>	0.65	-	V
	I <sub>F</sub> = 10 A			0.83	1.02	
	I <sub>F</sub> = 5 A	T <sub>A</sub> = 125 °C		0.57	-	
	I <sub>F</sub> = 10 A			0.67	0.75	
Reverse current per diode	V <sub>R</sub> = 70 V	T <sub>A</sub> = 25 °C	I <sub>R</sub> <sup>(2)</sup>	1.5	-	μA
		T <sub>A</sub> = 125 °C		0.8	-	mA
	V <sub>R</sub> = 100 V	T <sub>A</sub> = 25 °C		-	500	μA
		T <sub>A</sub> = 125 °C		1.5	10	mA

**Notes**

- (1) Pulse test: 300  $\mu\text{s}$  pulse width, 1 % duty cycle  
 (2) Pulse test: Pulse width  $\leq 5\text{ ms}$

<b>THERMAL CHARACTERISTICS</b> ( $T_A = 25\text{ }^{\circ}\text{C}$ unless otherwise noted)				
PARAMETER		SYMBOL	V20M100M	UNIT
Typical thermal resistance	per diode	$R_{\theta JC}$	2.8	$^{\circ}\text{C/W}$
	per device		1.4	
	per device	$R_{\theta JA}^{(1)(2)}$	40	

**Notes**

- (1) The heat generated must be less than the thermal conductivity from junction-to-ambient  $dP_D/dT_J < 1/R_{\theta JA}$   
 (2) Free air, without heatsink

<b>ORDERING INFORMATION</b> (Example)					
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
TO-220AB	V20M100M-E3/4W	1.88	4W	50/tube	Tube

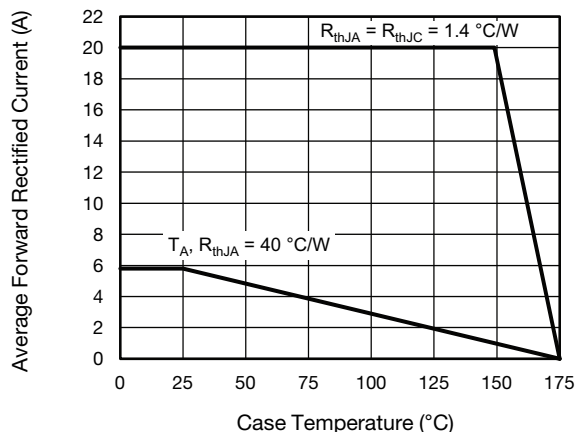
**RATINGS AND CHARACTERISTICS CURVES** ( $T_A = 25\text{ }^{\circ}\text{C}$  unless otherwise noted)


Fig. 1 - Maximum Forward Current Derating Curve

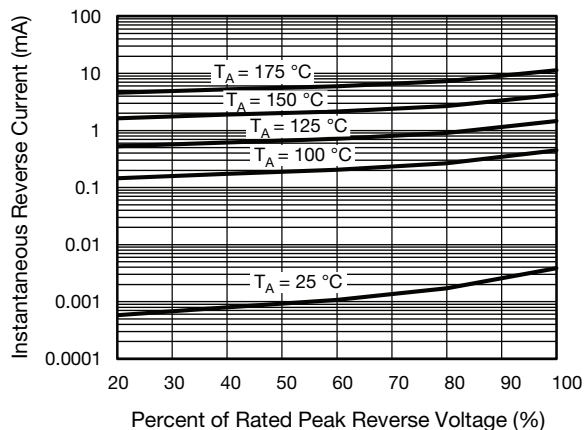


Fig. 4 - Typical Reverse Characteristics Per Diode

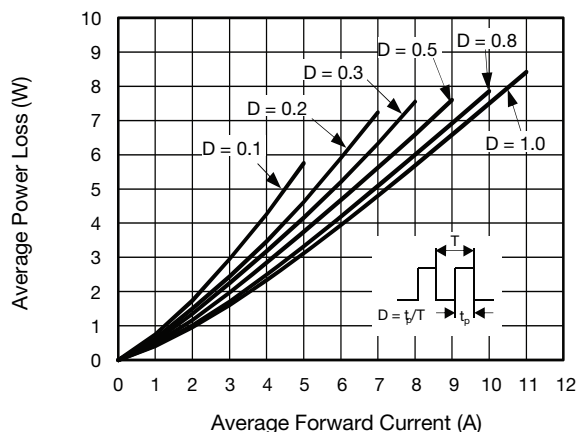


Fig. 2 - Forward Power Loss Characteristics Per Diode

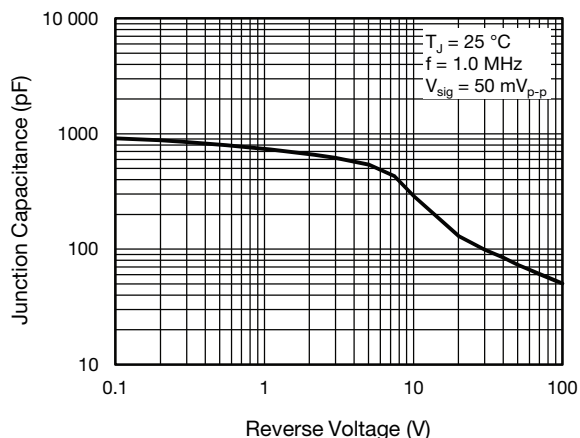


Fig. 5 - Typical Junction Capacitance Per Diode

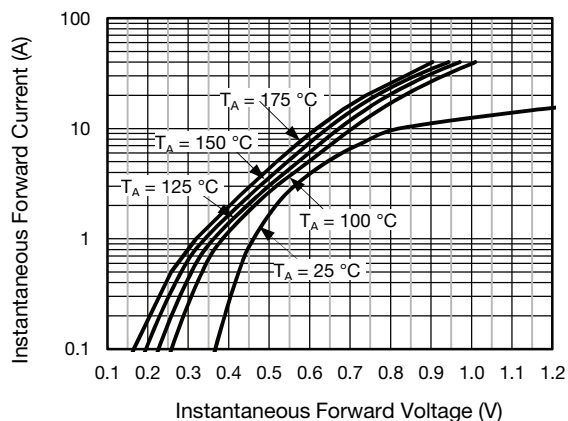


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

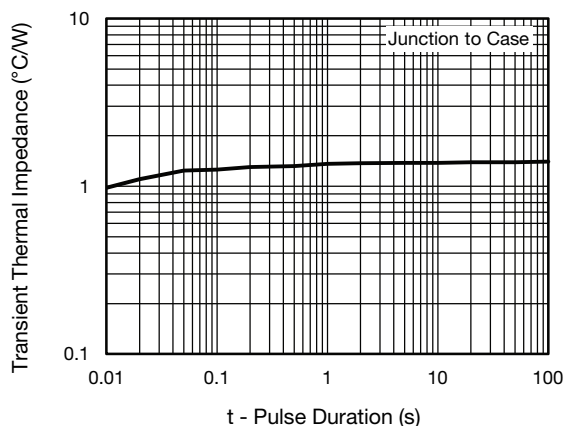
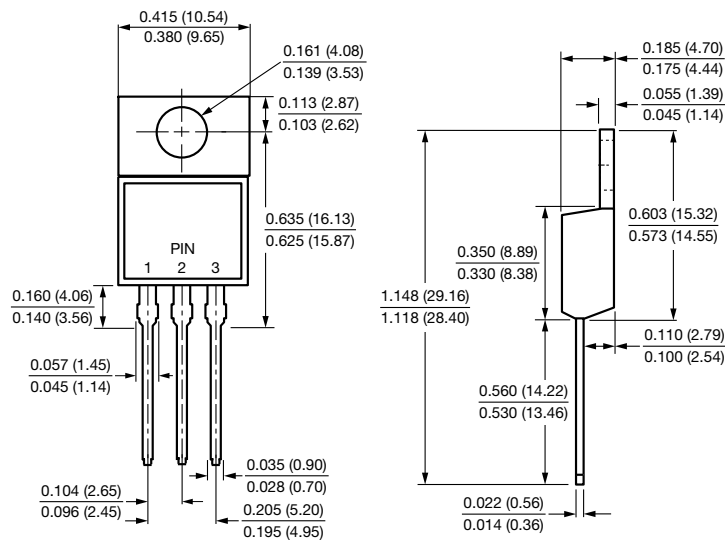


Fig. 6 - Typical Transient Thermal Impedance Per Device



PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

TO-220AB





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